RICOH

600 nA Iq Low Quiescent Current Boost DC/DC Converter for Energy Harvester

OVERVIEW

R1810x is a boost DC/DC converter for electrical power storage devices, especially dedicated for 1 cell photovoltaic energy harvester since the start-up voltage is Typ.0.35V.

This product can start up with only 9uW, and applicable for charging 1 cell photovoltaic element. A system which is working under low-illuminance environment can be composed with the R1810x.

KEY BENEFITS

- Providing a low quiescent current (I_{Q_VOUT} =Typ.600 nA), and high efficiency (66%@ I_{OUT}=5 μA)
- Start up with low input energy, 9 μW (low illuminance) is possible.
- Maximum power point control function is built-in.

KEY SPECIFICATIONS

- Start-up voltage: Typ. 0.35V Max. 0.50V (0°C ≤ Ta ≤ 65°C), Max. 0.55V (-40°C ≤ Ta ≤ 85°C)
- Input Voltage Range: 0.2 V to 2.1 V (VSET=2.7V)
- Output Voltage Range: 2.3 V to 4.5 V
- Output Voltage Accuracy: ±5.0%
- Low current consumption:
- Typ.600 nA (Ta = 25°C, at no load)
- Start-up power: 9 μ W (V_{MPSET} = 0.5V / V_{SET} = 2.6V)
- Maximum Power Point Control Voltage Setting: from 0.2V to 2.1V, in 50 mV increments
- Input Power Good Function
- Output Power Good Function

TYPICAL APPLICATION

APPLICATION



EFFICIENCY CURVE



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SELECTION GUIDE

Product name	Package	Quantity per Reel
R1810Zxxx\$-E2-F	WLCSP-15-P1	5,000 pcs
R1810Lxxx\$-E2	DFN2735-14	5,000 pcs

xxx: Select the combination Code number of the set output voltage (V_{SET}) and the set maximum power voltage (V_{MPSET}) ex. 001 Refer to the Product-specific Electrical Characteristics for detail information.

Set output power good low (PGL) (Refer to selection guide.)



DFN2735-14

3.5 x 2.7 x 0.6 (mm)

• Energy harvesting modules such as 1 cell photovoltaic element /thermoelectric power generation.

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SELECTION GUIDE

The set output voltage, the set maximum power point control voltage, and the output power good setting are user-selectable options.

Selection Guide

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
R1810Zxxx\$-E2-F	WLCSP-15-P1	5,000 pcs	Yes	Yes
R1810Lxxx\$-E2	DFN2735-14	5,000 pcs	Yes	Yes

xxx: Select the combination of the set output voltage (VSET) and the set maximum power point control voltage

(V_{MPSET}) by the code number. Ex. 001

Output voltage: from 2.3 V to 4.5 V in 0.1 V increments

Maximum power point control voltage: from 0.2 V to 2.1 V in 0.05 V increments

Refer to the Product-specific Electrical Characteristics for detail information.

* Contact our sales representatives for other codes.

It is recommended to set as $V_{SET} \ge V_{MPSET} + 1.0 V$.

\$: Set output power good low (PGL)⁽¹⁾

- A ; Vset x 80%
- B ; Vset x 70%
- C: Vset x 60%
- D; Vset x 50%

The accuracy of the OUTPG detection voltage depends on the output set voltage.

							Outpu	it pow	er go	<u>od lov</u>	<u>, OUT</u>	PG de	etectic	on acc	uracy									
			Set Output Voltage Vset [V]																					
	2.3 2.4 2.5 2.6 2.7 2.8 2.9 3 3.1 3.2 3.3 3.4 3.5 3.6 3.7 3.8 3.9 4 4.1 4.2 4.3 4.4										4.5													
	Α	-	-	-		5.0%						4.0%												
	В	-	-	-	-	1	-	-	•	5.0	5.0% 4.0%													
4	С	-	-	-	-	1	-	-	•	-	4.0%													
	D	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-		4.0%	

"-"; The OUTPG function cannot be used. please set the OUTPG pin to open.

⁽¹⁾ OUTPG outputs "Low" when the output is below the threshold of PGL according to the table above.



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BLOCK DIAGRAM



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PIN DESCRIPTIONS



Bottom View

Top View

R1810Z (WLCSP-15-P1) Pin Configuration



R1810L (DFN2735-14) Pin Configuration

* The tab on the bottom of the package enhances thermal performance and is electrically connected to GND (substrate level). The backside tab should be connected to the ground plane on the board.

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C. maked	Description	10	Pin No.			
Symbol	Description	1/0	R1810Z	R1810L		
VIN	Power Supply Input Pin. Apply input voltage between VIN pin and GND. Connect the input capacitor between the VIN pin and GND.	I	C3	5		
VOUT	Output voltage pin of step-up DC / DC converter. Connect the output load between VOUT pin and GND. Connect the output capacitor between VOUT pin and GND.	0	D1,E1	8		
INPG	Power good output pin for power input voltage (V _{IN}). "High" level of the output voltage for CMOS output is the output voltage (V _{OUT}) of the step-up DC / DC converter. Outputs "High" when V _{IN} exceeds V _{MPSET} and V _{OUT} exceeds V _{OUTUVLOR} ^{**1} . Please left open when not in use.	0	A1	13		
VREG	Output pin of step-up DC / DC converter (internal power supply) for startup. Supply voltage to the main DC / DC converter circuit that produces VOUT at startup. Please connect a capacitor between VREG pin and GND for voltage stabilization.	0	C1	11		
LX	The drain of the internal MOSFET. Connect an inductor between VIN pin and LX pin.	0	D2,D3	6		
VCP	Output pin of the startup internal step-up charge pump (internal power source). Supply voltage to the start-up DC / DC converter circuit that generates the VREG voltage at startup. Please connect a capacitor between the VCP pin and GND for voltage stabilization.	0	B1	12		
OUTPG	Power good output pin for V _{OUT} . "High" level of the output voltage for CMOS output is V _{OUT} . Outputs "High" when V _{OUT} is V _{OUTPGH} ^{#1} or higher, and outputs "Low" when V _{OUT} is V _{OUTPGL} ^{#1} or lower. Please left open when not in use.	0	A2	14		
TEST 1,2,3	Test pins for the IC. Be sure to connect to AGND.		C2,B2,A3	9,4,1		
AGND	Analog ground of the internal circuit. Please connect to the PGND and GND.	_	В3	2		
PGND	Power ground of the internal circuit. Please connect to the AGND and GND.	_	E2,E3	7		
NC	No connection. It is recommended to make it open to prevent short circuit with adjacent pins during mounting.	_	-	3,10		

R1810Z 、R1810L Pin Description

%1 : Refer to electrical characteristics.

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ABSOLUTE MAXIMUM RATINGS

Absolute M	aximum Ratings	(GN	ID = 0 V)
Symbol	Parameter	Rating	Unit
VIN	Input Pin Voltage	-0.3 to 2.3	V
V _{LX}	LX Pin Voltage	-0.3 to 6.5	V
Vout	Output Pin Voltage	-0.3 to 6.5	V
V _{REG}	Output Voltage of Boost DC to DC Converter for Start-up	-0.3 to 6.5	V
Vcp	Output Pin Voltage of Charge Pump Circuit	-0.3 to 6.5	V
VTEST1 to 3	Pin Voltage for Testing	-0.3 to 6.5	V
VINPG	INPG Pin Voltage	-0.3 to 6.5	V
I _{INPG}	INPG Pin Current	10	mA
Voutpg	OUTPG Pin Voltage	-0.3 to 6.5	V
IOUTPG	OUTPG Pin Current	10	mA
PD	Power Dissipation	Refer to the Power Diss in the supplementary	ipation item
Tj	Junction Temperature Range	-40 to 85	°C
Tstg	Storage Temperature Range	-55 to 125	°C

ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause permanent damage and may degrade the lifetime and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings are not assured.

RECOMMENDED OPERATING CONDITIONS

Recommended Operating Conditions

Symbol	Parameter	Rating	Unit
VIN	Input Voltage ⁽¹⁾	0.35 to 2.1	V
Та	Operating Temperature Range	-40 to 85	°C

RECOMMENDED OPERATING CONDITIONS

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if they are used over such conditions by momentary electronic noise or surge. The semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

⁽¹⁾ The lower limit of the input voltage depends on the set output voltage. Please refer to Page.22 for details.

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ELECTRICAL CHARACTERISTICS

The specifications surrounded by \square are guaranteed by design at $-40^{\circ}C \le Ta \le 85^{\circ}C$, not mass production tested.

R1810x Ele	ctrical Characteristics				(Ta	= 25°C)
Symbol	Parameter	Conditions	Тур.	Max.	Unit	
I _{Q_VOUT}	VOUT Pin Quiescent Current	VOUT Pin Quiescent Current $V_{IN} = 0.5V$, $V_{OUT} = 4.5 V$, at no switching				
Iq_vin	VIN Pin Quiescent Current	V _{IN} = 0.5 V, V _{OUT} = 4.5 V, at no switching		400		nA
Vout	Output Pin Voltage	VIN > VMP	V _{SET} ×0.95		V _{SET} ×1.05	V
VMD	Accuracy of Maximum	Vout = Vset, Vmpset ≥0.5V	-5		5	%
VMP	Power Point Control Voltage	Vout = Vset, Vmpset <0.5V	-50		50	mV
Voutpgh	OUTPG "High" Threshold Voltage	xxxA: 2.6V ≤ V _{SET} xxxB: 3.1V ≤ V _{SET} xxxC: 3.6V ≤ V _{SET} xxxD: 4.3V ≤ V _{SET}	V _{SET} × 0.87	V _{SET} × 0.90	Vsет × 0.93	v
	OUTPG "Low" Threshold	xxxA: 2.6V ≤ V _{SET} < 3.3V xxxB: 3.1V ≤ V _{SET} < 3.3V	Vset × (PGL -0.05)	V _{SET} × PGL	Vse⊤ × (PGL +0.05)	V
Voutpgl	Voltage	xxxA: 3.3V ≤ V _{SET} xxxB: 3.3V ≤ V _{SET} xxxC: 3.6V ≤ V _{SET} xxxD: 4.3V ≤ V _{SET}	Vset × (PGL -0.04)	V _{SET} × PGL	<u> </u>	v
VINPGH	INPG "High" Threshold Voltage		V _{MPSET} × 1.05			V
VINPGL	INPG "Low" Threshold Voltage				V _{MPSET} × 0.95	V
Voutuvlor	VOUTUVLO Release Voltage				2.11	V
VOUTUVLOF	VOUTUVLO Detection Voltage		1.55			V
Voutpgh	OUTPG "High" Output Voltage	Ιουτρg=-1μΑ	<u>Vsет</u> ×0.9			v
VINPGH	INPG "High" Output Voltage	IINPG=-1µA	V _{SET} ×0.9			V
VOUTPGL	OUTPG "Low" Output Voltage	IOUTPG=1µA			0.1	V
VINPGL	INPG "Low" Output Voltage	I _{INPG} =1µA			0.1	V

All test items listed under Electrical Characteristics are done under the pulse load condition (Tj \approx Ta = 25°C). Test circuit is operated with "Open Loop Control" (GND = 0 V), unless otherwise specified.

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The specifications surrounded by \square are guaranteed by design engineering at $-40^{\circ}C \le Ta \le 85^{\circ}C$

Product	Outpu	ut Voltage	e [V]	Maxim Cont	um Powe rol Voltag	er Point ge [V]	OUTPG"High" Detection Voltage [V]			
Name	Min. Typ. Max.		Min.	Тур.	Max.	Min.	Тур.	Max.		
R1810x003A	2.470	2.6	2.730	0.475	0.5	0.525	2.262	2.34	2.418	
R1810x004A	2.470	2.6	2.730	1.995	2.1	2.205	2.262	2.34	2.418	
R1810x005A	4.275	4.5	4.725	0.475	0.5	0.525	3.915	4.05	4.185	
R1810x006A	4.275	4.5	4.725	1.140	1.2	1.260	3.915	4.05	4.185	
R1810x007A	4.275	4.5	4.725	1.995	2.1	2.205	3.915	4.05	4.185	
R1810x013A	2.565	2.7	2.835	1.425	1.5	1.575	2.349	2.43	2.511	
R1810x016A	2.185	2.3	2.415	0.475	0.5	0.525	-	-	-	
R1810x017A	3.135	3.3	3.465	0.475	0.5	0.525	2.871	2.97	3.069	
R1810x018A	3.135	3.3	3.465	1.995	2.1	2.205	2.871	2.97	3.069	
R1810x019A	3.420	3.6	3.780	0.475	0.5	0.525	3.132	3.24	3.348	
R1810x022A	2.565	2.7	2.835	0.475	0.5	0.525	2.349	2.43	2.511	
R1810x023A	2.470	2.6	2.730	0.523	0.55	0.577	2.262	2.34	2.418	
R1810x024A	2.565	2.7	2.835	0.523	0.55	0.577	2.349	2.43	2.511	
R1810x025A	2.470	2.6	2.730	0.570	0.6	0.630	2.262	2.34	2.418	
R1810x026A	2.565	2.7	2.835	0.570	0.6	0.630	2.349	2.43	2.511	
R1810x027A	2.470	2.6	2.730	0.855	0.9	0.945	2.262	2.34	2.418	
R1810x028A	2.565	2.7	2.835	0.855	0.9	0.945	2.349	2.43	2.511	
R1810x029A	2.470	2.6	2.730	0.950	1.0	1.050	2.262	2.34	2.418	
R1810x030A	2.565	2.7	2.835	0.950	1.0	1.050	2.349	2.43	2.511	
R1810x031A	2.470	2.6	2.730	1.045	1.1	1.155	2.262	2.34	2.418	
R1810x032A	2.565	2.7	2.835	1.045	1.1	1.155	2.349	2.43	2.511	
R1810x033A	2.565	2.7	2.835	0.665	0.7	0.735	2.349	2.43	2.511	
R1810x034A	2.565	2.7	2.835	0.760	0.8	0.840	2.349	2.43	2.511	

R1810xxxxA Product-specific Electrical Characteristics

If VSET < 2.6V, the OUTPG function cannot be used.

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Draduat	OU	TPG"Lov	v"	INPG"High"	INPG"Low"
Product	Detecti	ion Voltag	ge [V]	Detection Voltage [V]	Detection Voltage [V]
Name	Min.	Тур.	Max.	Min.	Max.
R1810x003A	1.950	2.080	2.210	0.525	0.475
R1810x004A	1.950	2.080	2.210	2.205	1.995
R1810x005A	3.420	3.600	3.780	0.525	0.475
R1810x006A	3.420	3.600	3.780	1.260	1.140
R1810x007A	3.420	3.600	3.780	2.205	1.995
R1810x013A	2.025	2.160	2.295	1.575	1.425
R1810x016A	-	-	-	0.525	0.475
R1810x017A	2.508	2.640	2.772	0.525	0.475
R1810x018A	2.508	2.640	2.772	2.205	1.995
R1810x019A	2.736	2.880	3.024	0.525	0.475
R1810x022A	2.025	2.160	2.295	0.525	0.475
R1810x023A	1.950	2.080	2.210	0.578	0.523
R1810x024A	2.025	2.160	2.295	0.578	0.523
R1810x025A	1.950	2.080	2.210	0.630	0.570
R1810x026A	2.025	2.160	2.295	0.630	0.570
R1810x027A	1.950	2.080	2.210	0.945	0.855
R1810x028A	2.025	2.160	2.295	0.945	0.855
R1810x029A	1.950	2.080	2.210	1.050	0.950
R1810x030A	2.025	2.160	2.295	1.050	0.950
R1810x031A	1.950	2.080	2.210	1.155	1.045
R1810x032A	2.025	2.160	2.295	1.155	1.045
R1810x033A	2.025	2.160	2.295	0.735	0.665
R1810x034A	2.025	2.160	2.295	0.840	0.760

If VSET < 2.6V, the OUTPG function cannot be used.

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The specifications surrounded by \square are guaranteed by design engineering at $-40^{\circ}C \le Ta \le 85^{\circ}C$

Product	Outpu	ut Voltage	e [V]	Maxim Cont	um Powe rol Voltag	er Point ge [V]	OUTPG"High" Detection Voltage [V]			
Name	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	
R1810x003B	2.470	2.6	2.730	0.475	0.5	0.525	-	-	-	
R1810x004B	2.470	2.6	2.730	1.995	2.1	2.205	-	-	-	
R1810x005B	4.275	4.5	4.725	0.475	0.5	0.525	3.915	4.05	4.185	
R1810x006B	4.275	4.5	4.725	1.140	1.2	1.260	3.915	4.05	4.185	
R1810x007B	4.275	4.5	4.725	1.995	2.1	2.205	3.915	4.05	4.185	
R1810x013B	2.565	2.7	2.835	1.425	1.5	1.575	-	-	-	
R1810x017B	3.135	3.3	3.465	0.475	0.5	0.525	2.871	2.97	3.069	
R1810x018B	3.135	3.3	3.465	1.995	2.1	2.205	2.871	2.97	3.069	
R1810x019B	3.420	3.6	3.780	0.475	0.5	0.525	3.132	3.24	3.348	
R1810x022B	2.565	2.7	2.835	0.475	0.5	0.525	-	-	-	
R1810x023B	2.470	2.6	2.730	0.523	0.55	0.577	-	-	-	
R1810x024B	2.565	2.7	2.835	0.523	0.55	0.577	-	-	-	
R1810x025B	2.470	2.6	2.730	0.570	0.6	0.630	-	-	-	
R1810x026B	2.565	2.7	2.835	0.570	0.6	0.630	-	-	-	
R1810x027B	2.470	2.6	2.730	0.855	0.9	0.945	-	-	-	
R1810x028B	2.565	2.7	2.835	0.855	0.9	0.945	-	-	-	
R1810x029B	2.470	2.6	2.730	0.950	1.0	1.050	-	-	-	
R1810x030B	2.565	2.7	2.835	0.950	1.0	1.050	-	-	-	
R1810x031B	2.470	2.6	2.730	1.045	1.1	1.155	-	-	-	
R1810x032B	2.565	2.7	2.835	1.045	1.1	1.155	-	-	-	
R1810x033B	2.565	2.7	2.835	0.665	0.7	0.735	-	-	-	
R1810x034B	2.565	2.7	2.835	0.760	0.8	0.840	-	-	-	

R1810xxxxB Product-specific Electrical Characteristics

lf	VSET	<	3.1V,	the	OUTPG	function	cannot be	used.
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Dreadurat	OU	TPG"Lov	v"	INPG"High"	INPG"Low"		
Product	Detect	ion Volta	ge [V]	Detection Voltage [V]	Detection Voltage [V]		
Name	Min.	Тур.	Max.	Min.	Max.		
R1810x003B	-	-	-	0.525	0.475		
R1810x004B	-	-	-	2.205	1.995		
R1810x005B	2.970	3.150	3.330	0.525	0.475		
R1810x006B	2.970	3.150	3.330	1.260	1.140		
R1810x007B	2.970	3.150	3.330	2.205	1.995		
R1810x013B	-	-	-	1.575	1.425		
R1810x017B	2.178	2.310	2.442	0.525	0.475		
R1810x018B	2.178	2.310	2.442	2.205	1.995		
R1810x019B	2.376	2.520	2.664	0.525	0.475		
R1810x022B	-	-	-	0.525	0.475		
R1810x023B	-	-	-	0.578	0.523		
R1810x024B	-	-	-	0.578	0.523		
R1810x025B	-	-	-	0.630	0.570		
R1810x026B	-	-	-	0.630	0.570		
R1810x027B	-	-	-	0.945	0.855		
R1810x028B	-	-	-	0.945	0.855		
R1810x029B	-	-	-	1.050	0.950		
R1810x030B	-	-	-	1.050	0.950		
R1810x031B	-	-	-	1.155	1.045		
R1810x032B	-	-	-	1.155	1.045		
R1810x033B	-	-	-	0.735	0.665		
R1810x034B	-	-	-	0.840	0.760		

If VSET < 3.1V, the OUTPG function cannot be used.

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The specifications surrounded by \square are guaranteed by design engineering at $-40^{\circ}C \le Ta \le 85^{\circ}C$

Product	Output Voltage [V]		Maximum Power Point Control Voltage [V]			OUTPG"High" Detection Voltage [V]			
Name	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.
R1810x005C	4.275	4.5	4.725	0.475	0.5	0.525	3.915	4.05	4.185
R1810x006C	4.275	4.5	4.725	1.140	1.2	1.260	3.915	4.05	4.185
R1810x007C	4.275	4.5	4.725	1.995	2.1	2.205	3.915	4.05	4.185
R1810x017C	3.135	3.3	3.465	0.475	0.5	0.525	-	-	-
R1810x018C	3.135	3.3	3.465	1.995	2.1	2.205	-	-	-
R1810x019C	3.420	3.6	3.780	0.475	0.5	0.525	3.132	3.24	3.348

R1810xxxxC Product-specific Electrical Characteristics

Product	OUTPG"Low" Detection Voltage [V]			INPG"High" Detection Voltage [V]	INPG"Low" Detection Voltage [V]
Name	Min.	Тур.	Max.	Min.	Max.
R1810x005C	2.520	2.700	2.880	0.525	0.475
R1810x006C	2.520	2.700	2.880	1.260	1.140
R1810x007C	2.520	2.700	2.880	2.205	1.995
R1810x017C	-	-	-	0.525	0.475
R1810x018C	-	-	-	2.205	1.995
R1810x019C	2.016	2.160	2.304	0.525	0.475

If VSET < 3.6V, the OUTPG function cannot be used.

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The specifications surrounded by \square are guaranteed by design engineering at $-40^{\circ}C \le Ta \le 85^{\circ}C$

R1810xxxxD Product-specific Electrical Characteristics

Product	Output Voltage [V]			Maximum Power Point Control Voltage [V]			OUTPG"High" Detection Voltage [V]		
Name	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.
R1810x005D	4.275	4.5	4.725	0.475	0.5	0.525	3.915	4.05	4.185
R1810x006D	4.275	4.5	4.725	1.140	1.2	1.260	3.915	4.05	4.185
R1810x007D	4.275	4.5	4.725	1.995	2.1	2.205	3.915	4.05	4.185
R1810x019D	3.420	3.6	3.780	0.475	0.5	0.525	-	-	-

Product	OUTPG"Low" Detection Voltage [V]		v" ge [V]	INPG"High" Detection Voltage [V]	INPG"Low" Detection Voltage [V]
Name	Min.	Тур.	Max.	Min.	Max.
R1810x005D	2.070	2.250	2.430	0.525	0.475
R1810x006D	2.070	2.250	2.430	1.260	1.140
R1810x007D	2.070	2.250	2.430	2.205	1.995
R1810x019D	-	-	-	0.525	0.475

If VSET < 4.3V, the OUTPG function cannot be used.

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TYPICAL APPLICATION CIRCUIT





Recommended External Components

Symbol	Descriptions			
CIN	Ceramic Capacitor, 22 µF or more			
Сср	Ceramic Capacitor, 0.022µF or more			
Creg	Ceramic Capacitor, 4.7 µF or more			
<u></u>	Ceramic Capacitor, 4.7 μF or more			
COUT	Large-capacity Electrical Storage Device			
L	Inductor, 22 µH			

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TECHNICAL NOTES

The performance of the IC largely depends on the external components and circuitry layout. Especially, design the circuit carefully not to exceed each rating (voltage, current, power) for each component and the IC and consider the best layout pattern.

Use a ceramic capacitor with low ESR (equivalent series resistance). We recommend 22 μ F as CIN which is set between V_{IN} and GND.

We recommend 4.7uF ceramic capacitor or 10uF or more ceramic capacitor with large capacity of electrical storage device as COUT. The capacitors should cover the operating temperature range, and effective capacitance should be more than our recommendation capacity with 0 bias. Note that insulation resistance should not be too small. If insulation resistance is small, the leakage current may increase. Such a system cannot be recommended. (Refer to Page.24, 31)

We recommend an inductor with equal or more current rating (400mA or more), ESR, DC superimposition characteristics as our recommendation part. If ESR is large, or bad DC superimposition characteristics may lead to the bad efficiency. If the current rating is too small, the inductor may be broken down.

If other than GND level is connected to the TEST1,2,3 pins, by the shoot current of logic circuits inside the IC, consumption current may increase. Make sure to connect these pins to the ground level.

OPERATION

Boost DC/DC Converters For Energy Harvesting

Generally, boost DC/DC converters are used to make a suitable voltage for MCU and logic circuits by boost the input voltage. The R1810s is not a general boost DC to DC converter, but it is dedicated for energy harvesting, in other words, the power generated by a photovoltaic element is converted and accumulated to an electrical storage device with high efficiency. By intermittent operation by the power from the electrical storage device, the system can operate continuously without using a primary battery or power supply. The R1810x has the function of the maximum power point control to generate power at the best suitable voltage point. To realize single cell photovoltaic element base, the start-up voltage is 0.5V and once after start-up, even if the input voltage goes down to 0.2V, keeping on the operation is possible. Furthermore, start-up and charging to an electrical storage device with only 9uW input power, the system which operates under the low illuminance condition, can be built.

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Maximum Power Point Control



The R1810x converts the power from the photovoltaic cell at the voltage (V_{MP}), which is the maximum power generation possible point, and transferred to the power to C_{OUT} .

In other words, when the input voltage of the R1810x increases by the power from a photovoltaic element, and when the voltage reaches maximum power voltage (V_{MP}), switching operation starts and the R1810x transfers power to the C_{OUT} side.

In case that the power transfer amount exceeds the supplied power from the photovoltaic element, the input voltage decreases by switching. Then, when the voltage of V_{IN} becomes lower than V_{MP} , the next switching stops and C_{IN} is charged by the photovoltaic element and the voltage of V_{IN} increases. When the input voltage reaches the V_{MP} again, the R1810x transfers power to C_{OUT} side. By repeating this operation enables transferring power to the C_{OUT} side with keeping the maximum power generation point of the photovoltaic element.

Supplemental Remarks: If the photovoltaic power supply is low while the secondary capacitor is charged with the photovoltaic cell, the input voltage (V_{IN}) will fall at every energy transfer point. The boost ratio can be big by connecting a bigger capacitance capacitor (C_{IN}), the efficiency at charging is also improved.

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Operation While The Output Voltage Is At Stable Set Output Voltage.



Output Voltage Waveform at stable set output voltage point

When the output voltage reaches to set output voltage, the operation of the R1810x is as follows: When the output voltage becomes higher than the set output voltage, even if V_{IN} voltage is higher than V_{MP} voltage, the switching stops. When the output voltage becomes equal to set V_{OUT} voltage by a load, the switching resumes. By repeating this operation, the output voltage is maintained as the set output voltage.

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No Light With Light Photovoltaic element VIN V_{SET} VOUT V_{SET} × PGL VOUTUVLOR INPG"L"Detect Delay V_{INPG}=V_{OUT} INPG 1.5s(Min.) INPG"H"Detect Delay 1.4ms(Typ.) V_{OUTPG}=V_{OUT} OUTPG OUTPG"H"Detect Delay OUTPG"L"Detect Delay 4ms(Typ.) 13ms(Typ.) Time

Power Good (PG) Function

When V_{OUT} exceeds V_{OUT} released voltage, V_{OUTUVLOR}, the INPG pin becomes "High" (= V_{OUT} level). Otherwise, the INPG pin holds "Low". There are two cases the INPG pin becomes from "High" to "Low". One is when V_{OUT} falls below the V_{OUTUVLO} detector threshold, V_{OUTUVLOF}, and the other is in the case that the switching stops for a certain time (Min. 1.5 sec.) (Refer to the charge above.). The halt of switching means V_{IN} voltage level is less than V_{MP} voltage, and the internal circuit recognizes the shading. If you do not use the INPG function, set the INPG pin to "Open".

Typ. 4ms from when the switching starts and the voltage of V_{OUT} exceeds 90% of V_{SET}, the OUTPG pin becomes "High". Depending on the PG pin voltage, the condition of the output can be judged, and sequence control is possible. While the OUTPG is "High", the output is same as set voltage. When the output becomes lower than the (PGL) of V_{SET}, the OUTPG pin becomes "Low". This preset value (PGL) can be selected from 50% and 80% with 10% increment depending on V_{SET}. Refer to the "*SELECTION GUIDE*" about PGL setting. OUTPG function operates with using the V_{OUT} voltage as the power supply, therefore regardless of the supply of V_{IN} voltage, the operation is possible. For example, supposed that a system substantially operates a few times a day, and a large capacitance electrical storage device is connected with C_{OUT}, even if V_{IN} voltage becomes too low, as long as V_{OUT} voltage is beyond the V_{OUTUVLO} released voltage (V_{OUTUVLOR}), OUTPG can maintain "High". However, if you use the OUTPG function, Please note that the VSET value varies in between 50% and 80% of the PGL value to ensure the minimum operating voltage of the OUTPG function. If you do not use the PG function, Set the OUTPG pin to "Open".

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Cold Start Function

When the start-up voltage or more voltage is input, initially the boost DC/DC converter for start-up operates. The internal power supply (V_{REG}) for main DC/DC converter's operation is generated by the built-in start-up boost DC/DC converter. When the main converter starts the operation and output voltage rises high enough, the internal power supply is generated from the output of the main DC/DC converter, then the boost DC/DC converter for startup stops the operation.



- ① Boost DC/DC converter for start-up operates and boost the power supply V_{REG} of internal circuits.
- ② When V_{REG} is beyond the threshold, the boost DC/DC converter for start-up stops, and the main DC/ DC converter starts the operation. While V_{REG} maintains more than a certain voltage, the main DC/ DC converter operates and boost V_{OUT} voltage.
- ③ Since the main DC/DC converter operates, the voltage of V_{REG} becomes down due to the consumption current of internal circuits. When the voltage of V_{REG} becomes lower than a certain voltage, the main DC/DC converter stops and the boost DC/DC converter for start-up boosts the voltage of V_{REG}.
- When the voltage of V_{REG} becomes more than the threshold, the boost DC/DC converter for start-up stops and the main DC/DC converter starts operation.
 By repeating ③ and ④, the main converter boosts the voltage of VOUT pin until set output voltage, V_{SET}.

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Output Voltage Feedback Control

Under the conditions that the cold start is completed and V_{OUT} is boosted by the main DC/DC converter, when the voltage of V_{OUT} reaches the $V_{OUTUVLO}$ released voltage, $V_{OUTUVLO}$, the internal power supply V_{REG} and V_{OUT} are connected. This allows the main DC/DC converter to continue the operation without returning to the cold start condition, and to boost the output voltage until the set output voltage efficiently.

Output Generation Function



The R1810x stops boost operation when the output voltage exceeds V_{SET} . The output voltage (V_{OUT}) is tied to the internal power supply V_{REG} by the output voltage feedback control. When the voltage of V_{OUT} becomes lower than V_{SET} due to the internal circuit consumption current or the external load current, the boost operation starts again until (V_{OUT}) exceeds V_{SET} . When a large capacitance electrical storage device described in "*TYPICAL APPLICATION CIRCUIT*" is connected, the ripple voltage will be extremely small.

Reverse Current Protection Function

While the main DC/DC converter is operating, when the high-side MOSFET turns on, C_{OUT} connected V_{OUT} pin is charged, but due to the boost DC/DC converter's topology, $V_{IN} < V_{OUT}$ is true. After the charge is transferred to the output capacitor, when the reverse condition of V_{OUT} and V_{IN} is detected by comparing Lx and V_{OUT} , the R1810x turns off the high-side driver not to flow the reverse current. By shading, the power generation level by a photovoltaic element decreases, the charge of C_{IN} consumes by the consumption current of the IC and input voltage, V_{IN} gradually decreases. Even if the input voltage is zero, reverse current protection function can operate. If input voltage becomes lower than output voltage, V_{OUT} , by the reverse current protection function, the storage charge of C_{OUT} or a large capacitance electrical storage device is not drained in reverse.

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Application Information

Set Output Voltage and Input Voltage Range.

Depending on the setting value of the output voltage, the lower limit of the operable input voltage after the IC start-up is different.

Refer to the table below.

V _{SET} [V]	Input Voltage Range [V]
$2.3 \le V_{SET} \le 2.7$	$0.20 \le V_{IN} \le 2.10$
$2.3 \le V_{SET} \le 3.3$	$0.25 \le V_{IN} \le 2.10$
$2.3 \le V_{\text{SET}} \le 3.6$	$0.30 \le V_{IN} \le 2.10$
$2.3 \le V_{SET} \le 4.5$	0.35 ≤ V _{IN} ≤ 2.10

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Case 1: The R1810 is Connected to a Photovoltaic Element.

In Figure 1, 2 shown below are graphs of the input voltage dependence of the output voltage of the R1810 series.

When the R1810 is connected to an energy harvesting element (photovoltaic element), the input voltage V_{IN} depends on the power generation amount of the photovoltaic device and the load current.

When the voltage, V_{OUT} of the R1810 reaches V_{SET} , V_{IN} becomes the value $V_{IN}1$, which is determined by the relationship between the IV curve of the photovoltaic element and the quiescent VIN pin current (400nA) of R1810. (Fig. 3).

Input voltage $V_{IN}1$ is higher than V_{MP} . Therefore, when the switching is resumed, the average value of V_{OUT} will be higher than V_{SET} . When the input charge is consumed by the switching and V_{IN} drops, V_{OUT} is controlled by the V_{MP} again, and the average value of V_{OUT} drops to the nominal value.

If the amount of the power generated by the photovoltaic element is greater than the power consumed by the switching of the R1810, even if the switching is resumed, V_{IN} does not drop to V_{MP} , the average value of V_{OUT} rises. The graphs shown below are typical characteristics of the average value of V_{OUT} .

Select the device connected to the R1810 which can operate with the average value of VOUT.



Figure 1 : Input voltage dependence of the average value of the output voltage.

Figure 2 : Input voltage dependence of Bottom voltage $^{(\ast)}$ of output voltage.

- * Bottom Voltage ; Minimum value of the output ripple.
- Figure 3 : Characteristics of Photovoltaic Elements.

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Case 2: The R1810 is connected to a Large-Capacity Power Storage Device.

If the capacitance value of ceramic capacitor is small, output ripple becomes large, then the output ripple may exceed the voltage rating of the storage battery or rear-stage devices.

Please adjust the set output voltage and the value of the ceramic capacitor not to exceed the voltage rating with considering the ripple with the total capacity that can be calculated with the ceramic capacitor and the storage battery.

The guideline for the output ripple value from the total capacity of the ceramic capacitor and storage battery is calculated by the next formula.

1.35 ÷ C[μ F](Total Capacitance Value) ÷ (V_{IN}[V] - V_{OUT}[V]) + V_{OUT}[V] < V_{ABSOLUTE}[V](Absolute maximum rating value)

Manufacturer	Product	Part#	Capacity	Туре	Notes
TDK	CeraCharge™	PCT1912M101AC	100.046	All-solid-state	CeraCharge™ is a trademark of
IDK		BCTTOTZWITUTAG	τουμΑπ	Li-ion	TDK.
Nichicon	SLB series	SLB03070LR35	350µAh	LiB	
NGK	EnerCera®	ET1210C-R ET2016C-R ET271704P-H	5mAh 25mAh 5mAh	LiB	EnerCera® is a trademark of NGK.
Murata	CT series	CT04120	3mA	LiB	

Recommended example of large-capacity power storage device

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Case 3: The R1810 is used with a Sensor.



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Top Layer R1810L (DFN2735-14) Board Layout Diagram



Bottom Layer

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R1810Z (WLCSP-15-P1) Board Layout Diagram

PCB Layout

R1810x EA-423-210511



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Notes for PCB Layout.

Since large current may flow through the V_{IN} , V_{REG} , V_{OUT} , AGND, and PGND wiring, if the impedance of the wiring is high, unexpected noise or the unstable operation may result. Therefore, the impedance of wiring should be as low as possible.

As for C_{IN}, C_{CP}, and C_{OUT}, make the wiring as short as possible to the VIN pin, VCP pin, and VOUT pin, respectively.

Connect the AGND and PGND with low impedance point of the same board layer as the layer mounted the IC.

Be sure to leave the NC pin node to "Open".

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TYPICAL CHARACTERISTICS

Note: Typical Characteristics are just reference data; not guaranteed with the value shown in the graphs. 1) Efficiency vs. Output Current Ta = 25° C



2) Input Voltage vs. Output Voltage V_{SET} = 2.6V, V_{MP} = 0.5V Ta = 25°C Bottom Voltage



3) Operating Quiescent Current vs. Temperature V_{MP} = 0.5V



 V_{SET} = 2.6V, V_{MP} = 0.5V Ta = 25°C Average(Ripple Included)



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4) Operating Quiescent Current vs. Temperature V_{SET} = 2.6V, V_{MP} = 0.5V









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7) Start-up by the power generation element 1 R1810Z003A, Photovoltaic Element = AM-30-11C (14.0 × 13.0mm) $V_{SET} = 2.6V$, $V_{MP} = 0.5V$, $C_{OUT} = 1mF$

Ta = 25°C



8) Start-up by the power generation element 2 R1810Z003A , Photovoltaic Element = FDSC-FSC6FG (44.5 × 40.5mm) V_{SET} = 2.6V, V_{MP} = 0.5V, C_{OUT} = 1mF





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Test Circuit



[Components list for our evaluation]

Symbol	Part#	Description
CIN	C1608JB1A226M	22 µF, Ceramic Capacitor
C _{CP}	GRM155R71E223K	0.022 μF, Ceramic Capacitor
CREG	C1608JB1E475K	4.7 μF, Ceramic Capacitor
Соит	C1608JB1E475K	4.7 μF, Ceramic Capacitor
L	VLCF4028T-220MR72-2	22 μH, Inductor

POWER DISSIPATION

WLCSP-15-P1

PD-WLCSP-15-P1-(8585)-JE-A

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51.

Measurement Conditions

ltem	Measurement Conditions
Environment	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)
Board Dimensions	101.5 mm x 114.5 mm x 1.6 mm
Copper Ratio	Outer Layer (First Layer): 10% Inner Layers (Second and Third Layers): 99.5 x 99.5mm 100% Outer Layer (Fourth Layer): 10%

Measurement Result

(Ta = 25°C, Tjmax = 85°C)

Item	Measurement Result
Power Dissipation	710 mW
Thermal Resistance (θja)	θja = 84°C/W

θja: Junction-to-Ambient Thermal Resistance



Power Dissipation vs. Ambient Temperature



Measurement Board Pattern

PACKAGE DIMENSIONS

WLCSP-15-P1

DM-WLCSP-15-P1-JE-A



UNIT: mm

i



WLCSP

VI-160823

No.	Inspection Items	Inspection Criteria	Figure
1	Package chipping	A≥0.2mm is rejected B≥0.2mm is rejected C≥0.2mm is rejected And, Package chipping to Si surface and to bump is rejected.	B ↓ C
2	Si surface chipping	A≥0.2mm is rejected B≥0.2mm is rejected C≥0.2mm is rejected But, even if A≥0.2mm, B≤0.1mm is acceptable.	B to the second
3	No bump	No bump is rejected.	
4	Marking miss	To reject incorrect marking, such as another product name marking or another lot No. marking.	
5	No marking	To reject no marking on the package.	
6	Reverse direction of marking	To reject reverse direction of marking character.	
7	Defective marking	To reject unreadable marking. (Microscope: X15/ White LED/ Viewed from vertical direction)	
8	Scratch	To reject unreadable marking character by scratch. (Microscope: X15/ White LED/ Viewed from vertical direction)	
9	Stain and Foreign material	To reject unreadable marking character by stain and foreign material. (Microscope: X15/ White LED/ Viewed from vertical direction)	

POWER DISSIPATION

DFN2735-14

PD-DFN2735-14-(8585)-JE-A

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51.

Measurement Conditions

ltem	Measurement Conditions
Environment	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm
Copper Ratio	Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square
Through-holes	φ 0.3 mm × 30 pcs

Measurement Result

(Ta = 25°C, Tjmax = 85°C)

Item	Measurement Result
Power Dissipation	2500 mW
Thermal Resistance (θja)	θja = 24°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 4°C/W

θja: Junction-to-Ambient Thermal Resistance

wit: Junction-to-Top Thermal Characterization Parameter





Power Dissipation vs. Ambient Temperature

Measurement Board Pattern

PACKAGE DIMENSIONS

DFN2735-14

DM-DFN2735-14-JE-A





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